



#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(on)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
	160mΩ @ V <sub>GS</sub> = -4.5V	-2.4A
-20V	210mΩ @ V <sub>GS</sub> = -2.5V	-2.1A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters
- Motor Control

## Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

P-CHANNEL ENHANCEMENT MODE MOSFET

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/guality/product-definitions/

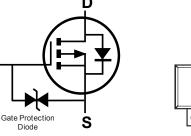
#### **Mechanical Data**

- Case: SOT23 (Standard)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish —Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)





Top View



Internal Schematic



Top View

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMG2301LK-7	SOT23 (Standard)	3,000/Tape & Reel
DMG2301LK-13	SOT23 (Standard)	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

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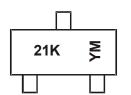
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## **Marking Information**



21K = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$ = Year (ex: D = 2016) M = Month (ex: 9 = September)

#### Date Code Key

Year	2016		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	D			J	K	L	М	Ν	0	Р	R	S
		-										
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Νον	Dec

#### Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-20	V		
Gate-Source Voltage			V <sub>GSS</sub>	±12	V
Continuous Drain Current (Note 6) $V_{GS}$ = -4.5VSteady State $T_A$ = +25°C $T_A$ = +70°C			ID	-2.4 -1.9	A
Maximum Continuous Body Diode Forward Current	ls	-1.12	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	-8	A		

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.84	W
Thermal Resistance, Junction to Ambient (Note 5) Steady State		R <sub>0JA</sub>	150	°C/W
Total Power Dissipation (Note 6)	PD	1.40	W	
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>θJA</sub>	91	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	



## Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified)

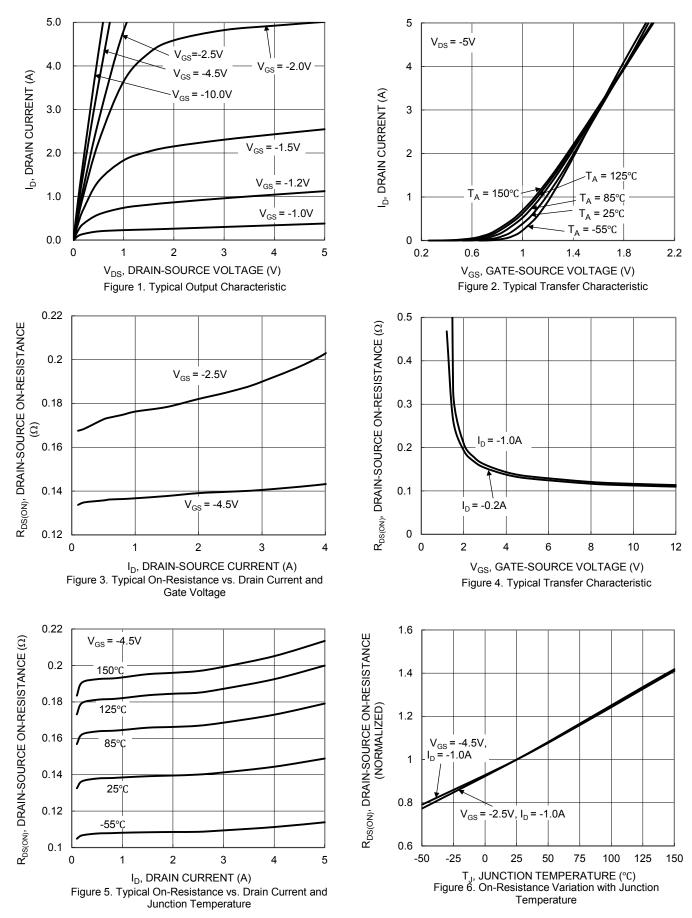
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						÷	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20			V	V <sub>GS</sub> = 0V, I <sub>D</sub> = -250µA	
Zero Gate Voltage Drain Current (T <sub>J</sub> = +25°C)	I <sub>DSS</sub>	_		-10	μA	V <sub>DS</sub> = -16V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	_		±10	μA	$V_{GS}$ = ±10V, $V_{DS}$ = 0V	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.3	-0.6	-1.0	V	$V_{DS}$ = $V_{GS}$ , $I_D$ = -250A	
			136	160		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -1.0A	
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	—	183	210	mΩ	V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -1.0A	
			229	298		V <sub>GS</sub> = -1.8V, I <sub>D</sub> = -0.2A	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.8	-1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1.0A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	156		pF		
Output Capacitance	C <sub>oss</sub>	_	36		pF	$V_{DS} = -6V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	28	_	pF		
Gate Resistance	R <sub>g</sub>	_	41		Ω	$V_{DS}$ = 0V, $V_{GS}$ = 0V, f = 1MHz	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	1.6		nC		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	3.4		nC	V <sub>DS</sub> = -6V,	
Gate-Source Charge	Q <sub>gs</sub>	_	0.3		nC	I <sub>D</sub> = -2.2A	
Gate-Drain Charge	Q <sub>gd</sub>	_	0.4		nC	1	
Turn-On Delay Time	t <sub>D(on)</sub>	_	3.2		ns		
Turn-On Rise Time	t <sub>R</sub>	_	7.4		ns	V <sub>DS</sub> = -6V, V <sub>GS</sub> = -4.5V,	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	11.0		ns	R <sub>GEN</sub> = 6 Ω, I <sub>D</sub> = -1A	
Turn-Off Fall Time	t <sub>F</sub>	_	10.5		ns		
Reverse Recovery Time	t <sub>RR</sub>	_	6.5		ns		
Reverse Recovery Charge	Q <sub>RR</sub>	_	0.8		nC	I <sub>F</sub> = -1.0A, di/dt = 100A/µs	

Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout.
Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



### DMG2301LK

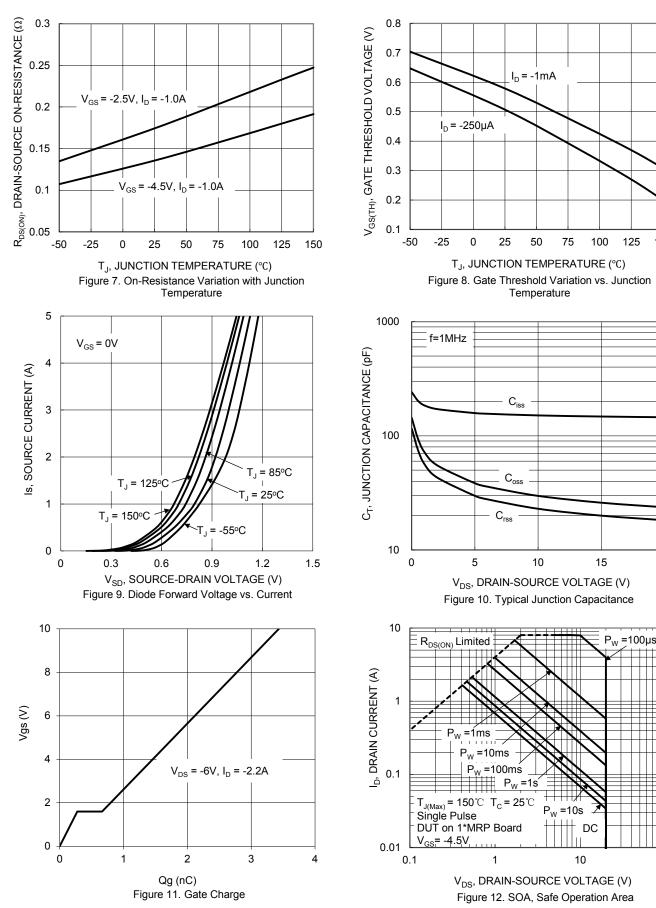




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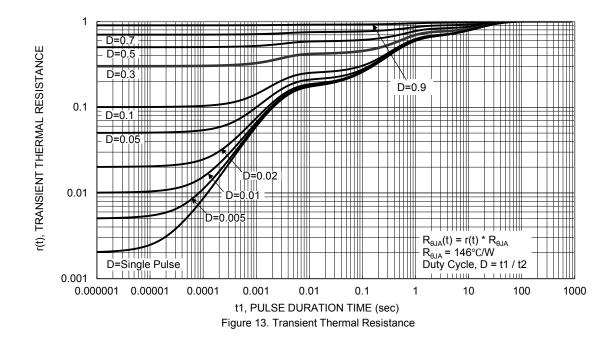
150

20



100

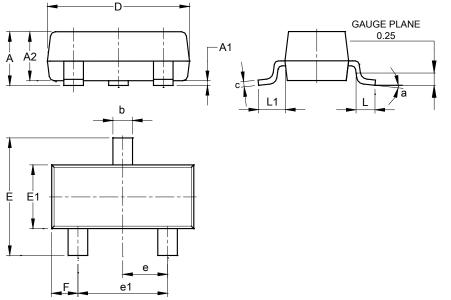






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

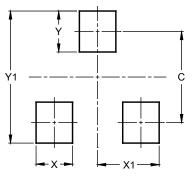


S	SOT23 (Standard)							
Dim	Min	Min Max						
Α	0.90	1.15	1.025					
A1	0.00	0.10	0.05					
A2	0.85	1.10	0.975					
b	0.30	0.51	0.40					
С	0.080	0.202	0.11					
D	2.80	3.00	2.90					
Е	2.25	2.55	2.40					
E1	1.20	1.40	1.30					
е	0.89	1.03	0.915					
e1	1.78	2.05	1.83					
F	0.40	0.60	0.535					
L1	0.45	0.61	0.55					
L	0.25	0.55	0.40					
а	0°	8°						
All Dimensions in mm								

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Standard)



Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			

SOT23 (Standard)



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